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Large Signal Modulation and Distortion in a Microwave Phase Shifter Based on Slow Light in a Semiconductor Waveguide

Yaohui Chen, Filip Öhman, and Jesper Mørk
COM.DTU Department of Communications, Optics & Materials, NanoDTU, Technical University of Denmark
Build. 345v, DK-2800 Kgs. Lyngby, Denmark, jm@com.dtu.dk

Abstract: We model slow-light propagation in an active semiconductor waveguide in the large modulation depth regime. Distortion from higher harmonics is countered by filtering and the regenerating properties of the device further increase the modulation depth.

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Introduction
It has been experimentally demonstrated that slow light propagation can be achieved in active semiconductor waveguides [1,2]. The physical phenomenon responsible for the effect is denoted coherent population oscillations and can be interpreted as a four-wave mixing effect [2,3] or alternatively as due to dynamical absorption saturation [2]. Due to the excitation of oscillations in the carrier density of the device the magnitude of the effect depends on the carrier lifetime and is restricted by a delay-bandwidth product. This points to narrow-bandwidth applications, such as the phase-shifting of a microwave signal e.g. for optical feeding of phased-array antennas or processing of optical clock signals. While measurements and analysis so-far were carried out in the small-signal regime [2,3], we here analyze the consequences for the signal quality when operating in the regime relevant to the applications where the modulation depth is close to 100 %.

Model
Based on the analytical model of [2] and a detailed model for carrier dynamics [4] we numerically investigate a strong intensity modulated optical signal passing through a reverse voltage controlled electro-absorption modulator (EAM). The numerical EAM model [4] is based on a microscopic model of the semiconductor carrier density dynamics, considering carrier density depletion, carrier heating (CH) and spectral-hole burning (SHB). The EAM has typical parameters: 0.18pJ saturation energy, 20ps carrier lifetime and small signal absorption 31.3dB at 2V reverse bias.

Results
As shown in Fig 1(a), an input optical signal at 15 GHz with 100 % modulation depth is strongly distorted at the output. A large phase shift is achieved at the rising edge of the signal, whereas zero phase shift is obtained at zero optical intensity. In order to reduce the distortion we use a low-pass filter (6-order Bessel filter with f_{3dB}=15GHz) to reshape the signal waveform, which also implies a change in the modulation depth. The EAM actually increases the modulation depth at the output of the waveguide due to the regenerating property of a saturable absorber [5]. The filtering also models the optical-to-electrical conversion taking place in a photodiode at the output. The resulting phase can be estimated from the 1st harmonic of the spectrum and its voltage dependence is shown in Fig. 2(a).

![Fig. 1. Temporal variation of power (normalized by mean value) at the output of the EAM (a) without and (b) with a filter after the EAM at transparency (0V) and at a reverse bias (2.15V). The input power was 25 mW.](image-url)
As demonstrated in Fig. 2(a), large signal modulation (100% modulation depth) introduces a small deviation between the numerical and the analytical result when the 1st harmonic is used to estimate the filtered output. However, the analytical results still provide a good approximation for the entire range of voltages. In order to estimate the effect of the higher harmonics, the phase shift corresponding to the time delay of the intensity peak is also included in Fig. 2(a). The difference between the peak shift (dashed line) and the 1st harmonic (red line) provides an estimate of the reduction of phase shift resulting from the restoration of the signal by the filter. In Fig. 2(b), a further comparison between the analytical and large signal results shows that while the deviation increases with modulation depth it remains small in absolute terms. The deviation for small modulation depth is attributed to CH and SHB effects included in the simulation, which are neglected in the analytical model.

The byproduct of large-signal modulation is the introduction of high order harmonics, as quantified by the second-harmonic suppression ratio (SHSR) shown in Fig. 3(a). The SHSR increases rapidly with input modulation depth but can to some degree be countered by filtering. The increase in output modulation depth resulting from the regenerating property of the saturable absorber [5] is seen in Fig. 3(b). This demonstrates that even including the filtering it is possible to keep, or even improve, the modulation depth at the output of the device.

Conclusions

The simulations in this work demonstrate that the application of phase delay based on slow light in an active semiconductor waveguide is feasible even in a large signal modulation case. The distortions to the signal introduced by the nonlinearities of the saturable absorber can be countered by appropriate filtering without reduction of the phase delay. Furthermore, a small signal analytical model is shown to also describe the large signal modulation case to a good approximation.

References